

74ABT574A

Octal D-type flip-flop; 3-state

Rev. 2 — 23 November 2012

Product data sheet

1. General description

The 74ABT574A high-performance BiCMOS device combines low static and dynamic power dissipation with high speed and high output drive.

The 74ABT574A is an 8-bit, edge triggered register coupled to eight 3-State output buffers. The clock input (CP) and output enable input ($\overline{OE}$) control gates, control the two sections of the device independently. The state of each data input (Dn, one set-up time before the Low-to-High clock transition) is transferred to the Q output of the corresponding flip-flop.

When $\overline{OE}$ is Low, the stored data appears at the outputs. When $\overline{OE}$ is High, the outputs are in the High-impedance "off" state, which means they do not drive or load the bus.

The 3-State output buffers are designed to drive heavily loaded 3-State buses, MOS memories, or MOS microprocessors. The active-Low Output Enable ($\overline{OE}$) controls all eight 3-State buffers independent of the clock operation.

2. Features and benefits

- 74ABT574A is flow-through pinout version of 74ABT374A
- Inputs and outputs on opposite side of package allow easy interface to microprocessors
- 3-State outputs for bus interfacing
- Power-on 3-state
- Power-on reset
- Common output enable
- Latch-up protection exceeds 500 mA per JESD78B class II level A
- ESD protection:
 - ◆ HBM JESD22-A114F exceeds 2000 V
 - ◆ MM JESD22-A115-A exceeds 200 V
- Live insertion/extraction permitted.

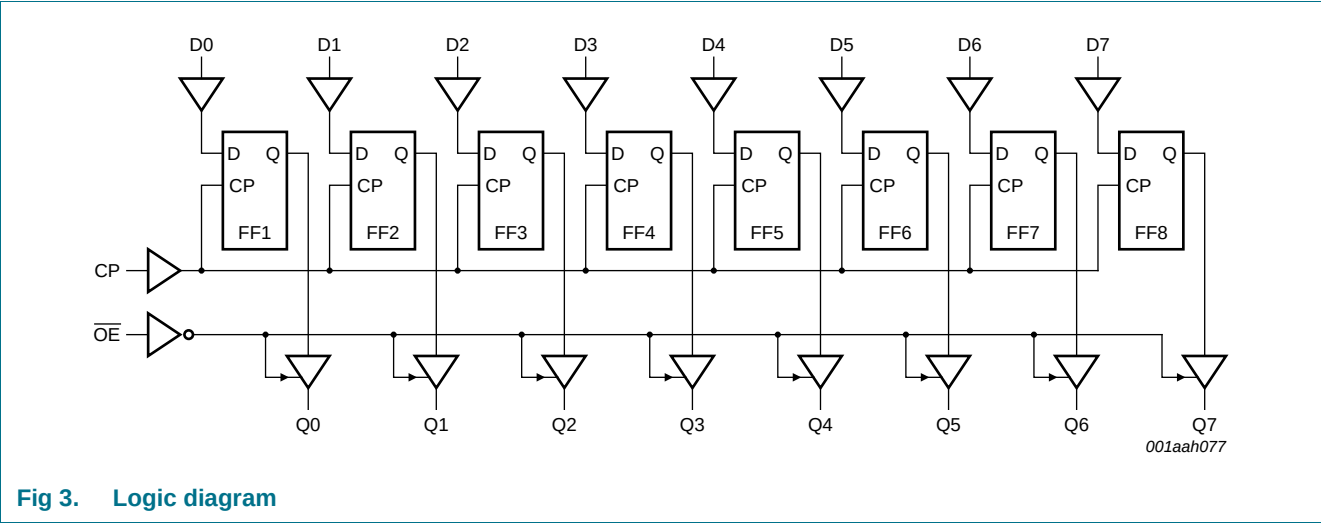
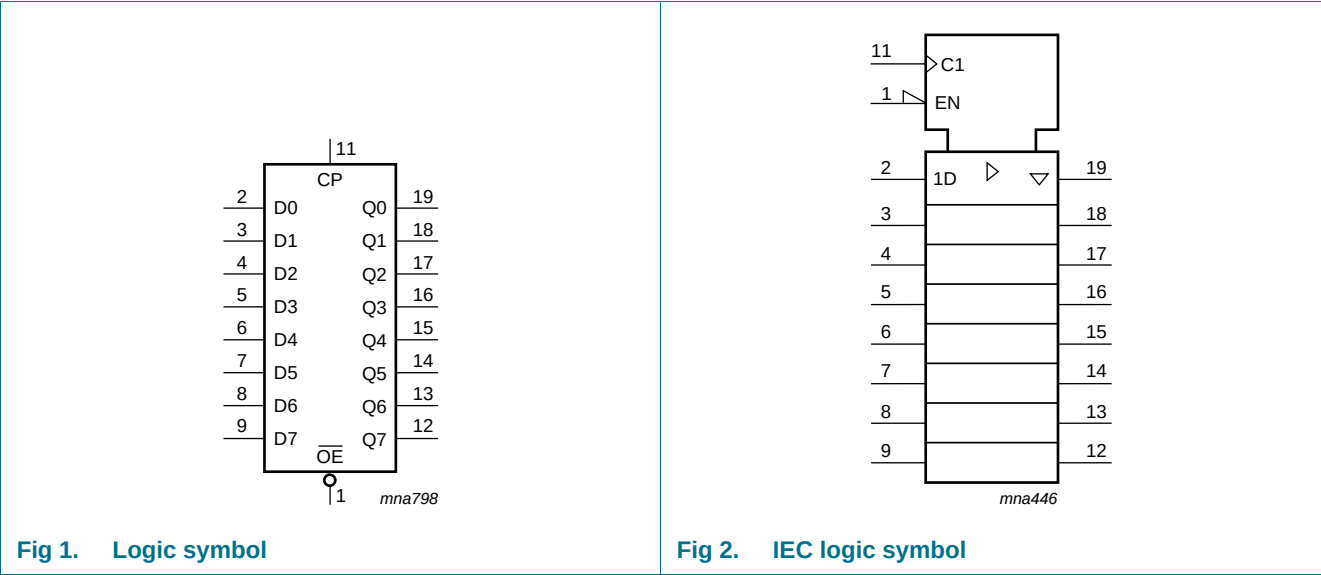


3. Ordering information

Table 1. Ordering information

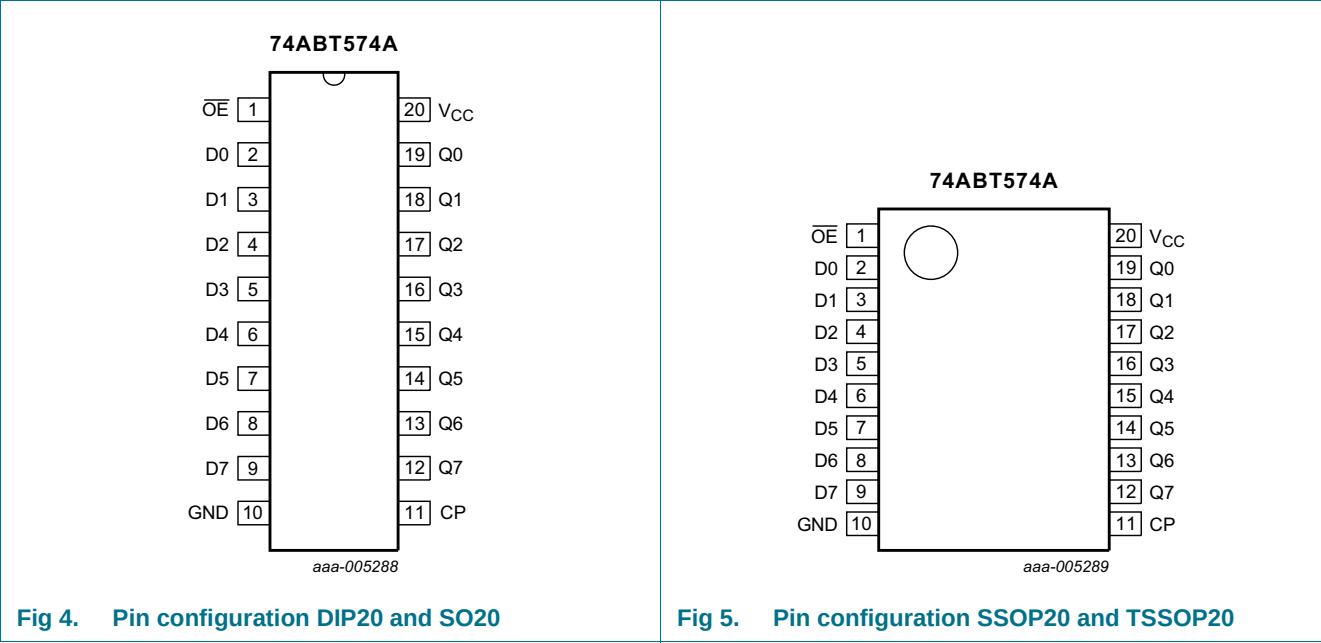
Type number	Package			
	Temperature range	Name	Description	Version
74ABT574AN	−40 °C to +85 °C	DIP20	plastic dual in-line package; 20 leads (300 mil)	SOT146-1
74ABT574AD	−40 °C to +85 °C	SO20	plastic small outline package; 20 leads; body width 7.5 mm	SOT163-1
74ABT574ADB	−40 °C to +85 °C	SSOP20	plastic shrink small outline package; 20 leads; body width 5.3 mm	SOT339-1
74ABT574APW	−40 °C to +85 °C	TSSOP20	plastic thin shrink small outline package; 20 leads; body width 4.4 mm	SOT360-1

4. Functional diagram



5. Pinning information

5.1 Pinning



5.2 Pin description

Table 2. Pin description

Symbol	Pin	Description
$\overline{OE}$	1	3-state output enable input (active LOW)
D0, D1, D2, D3, D4, D5, D6, D7	2, 3, 4, 5, 6, 7, 8, 9	data input
GND	10	ground (0 V)
CP	11	clock pulse input (active rising edge)
Q0, Q1, Q2, Q3, Q4, Q5, Q6, Q7	19, 18, 17, 16, 15, 14, 13, 12	3-state flip-flop output
V_{CC}	20	supply voltage

6. Functional description

Table 3. Function table^[1]

Operating mode	Input			Internal flip-flop	Output Qn
	OE	CP	Dn		
Load and read register	L	↑	l	L	L
	L	↑	h	H	H
Load register and disable output	H	↑	l	L	Z
	H	↑	h	H	Z

- [1] H = HIGH voltage level;
 h = HIGH voltage level one setup time before the HIGH-to-LOW CP transition;
 L = LOW voltage level;
 l = LOW voltage level one setup time before the HIGH-to-LOW CP transition;
 Z = high-impedance OFF-state;
 ↑ = LOW-to-HIGH clock transition.

7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		-0.5	+7.0	V
V _I	input voltage		^[1] -1.2	+7.0	V
V _O	output voltage	output in OFF-state or HIGH-state	^[1] -0.5	+5.5	V
I _{IK}	input clamping current	V _I < 0 V	-18	-	mA
I _{OK}	output clamping current	V _O < 0 V	-50	-	mA
I _O	output current	output in LOW-state	-	128	mA
T _j	junction temperature		^[2] -	150	°C
T _{stg}	storage temperature		-65	+150	°C

- [1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.
 [2] The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction temperatures which are detrimental to reliability. The maximum junction temperature of this integrated circuit should not exceed 150 °C.

8. Recommended operating conditions

Table 5. Operating conditions

Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V _{CC}	supply voltage		4.5	-	5.5	V
V _I	input voltage		0	-	V _{CC}	V
V _{IH}	HIGH-level input voltage		2.0	-	-	V
V _{IL}	LOW-level input voltage		-	-	0.8	V
I _{OH}	HIGH-level output current		-32	-	-	mA

Table 5. Operating conditions ...continued
 Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
I_{OL}	LOW-level output current		-	-	64	mA
$\Delta t/\Delta V$	input transition rise and fall rate		0	-	5	ns/V
T_{amb}	ambient temperature	in free air	-40	-	+85	°C

9. Static characteristics

Table 6. Static characteristics

Symbol	Parameter	Conditions	25 °C			−40 °C to +85 °C		Unit	
			Min	Typ	Max	Min	Max		
V _{IK}	input clamping voltage	V _{CC} = 4.5 V; I _{IK} = −18 mA	−1.2	−0.9	-	−1.2	-	V	
V _{OH}	HIGH-level output voltage	V _I = V _{IL} or V _{IH}							
		V _{CC} = 4.5 V; I _{OH} = −3 mA	2.5	2.9	-	2.5	-	V	
		V _{CC} = 5.0 V; I _{OH} = −3 mA	3.0	3.4	-	3.0	-	V	
		V _{CC} = 4.5 V; I _{OH} = −32 mA	2.0	2.4	-	2.0	-	V	
V _{OL}	LOW-level output voltage	V _{CC} = 4.5 V; I _{OL} = 64 mA; V _I = V _{IL} or V _{IH}	-	0.42	0.55	-	0.55	V	
V _{OL(pu)}	power-up LOW-level output voltage	V _{CC} = 5.5 V; I _O = 1 mA; V _I = GND or V _{CC}	[1]	-	0.13	0.55	-	0.55	V
I _I	input leakage current	V _{CC} = 5.5 V; V _I = V _{CC} or GND	-	±0.01	±1.0	-	±1.0	μA	
I _{OFF}	power-off leakage current	V _{CC} = 0 V; V _I or V _O ≤ 4.5 V	-	±5.0	±100	-	±100	μA	
I _{O(pu/pd)}	power-up/power-down output current	V _{CC} = 2.0 V; V _O = 0.5 V; V _I = GND or V _{CC} ; OE HIGH	[2]	-	±5.0	±50	-	±50	μA
I _{OZ}	OFF-state output current	V _{CC} = 5.5 V; V _I = V _{IL} or V _{IH}							
		V _O = 2.7 V	-	5.0	50	-	50	μA	
		V _O = 0.5 V	−50	−5.0	-	−50	-	μA	
I _{LO}	output leakage current	HIGH-state; V _O = 5.5 V; V _{CC} = 5.5 V; V _I = GND or V _{CC}	-	5.0	50	-	50	μA	
I _O	output current	V _{CC} = 5.5 V; V _O = 2.5 V	[3]	−180	−40	−180	−40	mA	
I _{CC}	supply current	V _{CC} = 5.5 V; V _I = GND or V _{CC}							
		outputs HIGH-state	-	100	250	-	250	μA	
		outputs LOW-state	-	24	30	-	30	mA	
		outputs disabled	-	100	250	-	250	μA	
ΔI _{CC}	additional supply current	per input pin; V _{CC} = 5.5 V; one input at 3.4 V; other inputs at V _{CC} or GND	[4]	-	0.5	1.5	-	1.5	mA

Table 6. Static characteristics ...continued

Symbol	Parameter	Conditions	25 °C			–40 °C to +85 °C		Unit
			Min	Typ	Max	Min	Max	
C _I	input capacitance	V _I = 0 V or V _{CC}	-	3	-	-	-	pF
C _O	output capacitance	outputs disabled; V _O = 0 V or V _{CC}	-	6	-	-	-	pF

- [1] For valid test results, do not load data into the flip-flops (or latches) after applying the power.
- [2] This parameter is valid for any V_{CC} between 0 V and 2.1 V, with a transition time of up to 10 ms. A transition time of up to 100 µs is permitted between V_{CC} = 2.1 V and V_{CC} = 5 V ± 10 %.
- [3] Do not test more than one output at a time, and the duration of the test must not exceed one second.
- [4] This characteristic is the increase in supply current for each input at 3.4 V.

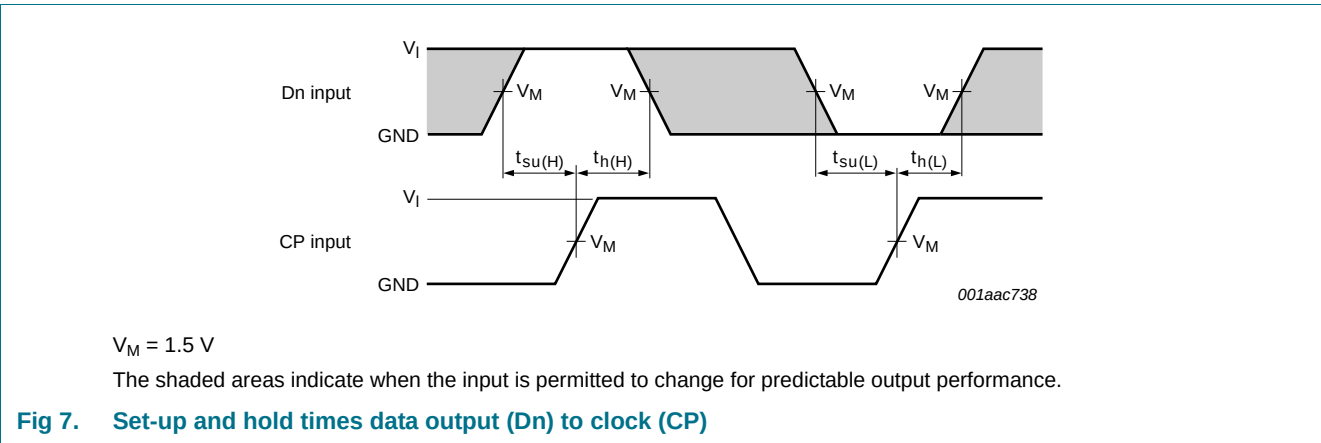
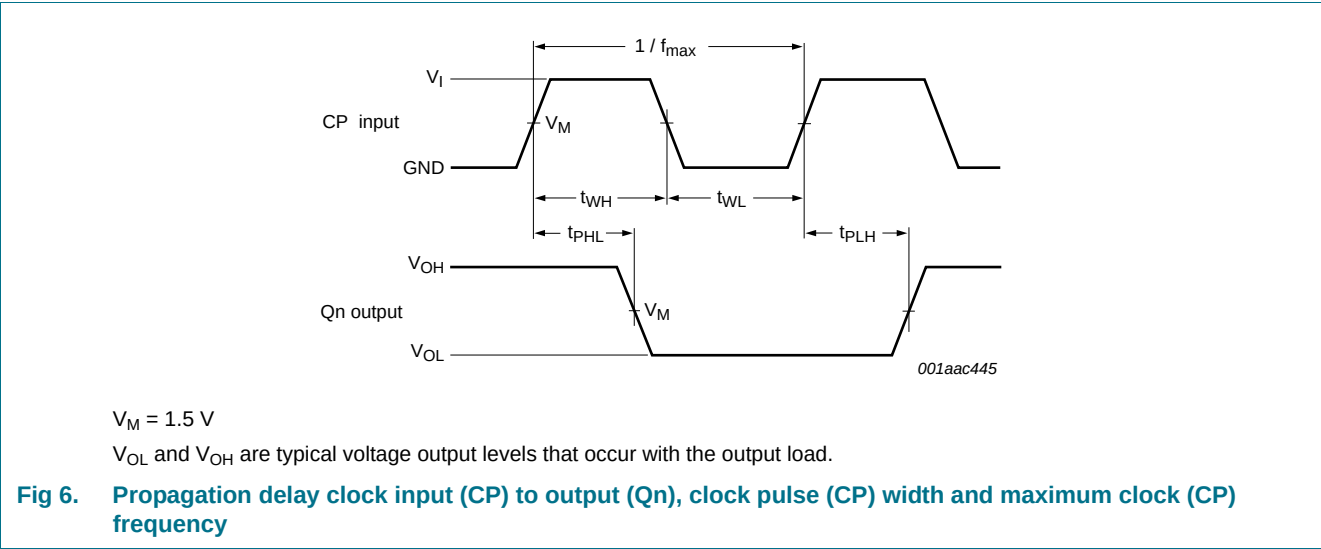
10. Dynamic characteristics

Table 7. Dynamic characteristics

GND = 0 V; for test circuit, see [Figure 9](#).

Symbol	Parameter	Conditions	25 °C; V _{CC} = 5.0 V			–40 °C to +85 °C; V _{CC} = 5.0 V ± 0.5 V		Unit
			Min	Typ	Max	Min	Max	
f _{max}	maximum frequency	see Figure 6	150	400	-	125	-	MHz
t _{PLH}	LOW to HIGH propagation delay	CP to Qn, see Figure 6	1.5	3.0	4.4	1.5	5.0	ns
t _{PHL}	HIGH to LOW propagation delay	CP to Qn, see Figure 6	2.0	3.4	4.7	2.0	5.1	ns
t _{PZH}	OFF-state to HIGH propagation delay	$\overline{\text{OE}}$ to Qn; see Figure 8	1.0	2.9	4.1	1.0	5.0	ns
t _{PZL}	OFF-state to LOW propagation delay	$\overline{\text{OE}}$ to Qn; see Figure 8	2.5	3.8	5.2	2.5	5.7	ns
t _{PHZ}	HIGH to OFF-state propagation delay	$\overline{\text{OE}}$ to Qn; see Figure 8	1.8	3.1	4.3	1.8	5.0	ns
t _{PLZ}	LOW to OFF-state propagation delay	$\overline{\text{OE}}$ to Qn; see Figure 8	1.4	2.6	3.8	1.4	4.0	ns
t _{su(H)}	set-up time HIGH	Dn to CP; see Figure 7	1.0	0.6	-	1.0	-	ns
t _{su(L)}	set-up time LOW	Dn to CP; see Figure 7	1.0	0.2	-	1.0	-	ns
t _{h(H)}	hold time HIGH	CP to Dn; see Figure 7	+1.0	–0.7	-	1.0	-	ns
t _{h(L)}	hold time LOW	CP to Dn; see Figure 7	+1.0	–0.4	-	1.0	-	ns
t _{WH}	pulse width HIGH	CP; see Figure 6	2.0	0.7	-	2.0	-	ns
t _{WL}	pulse width LOW	CP; see Figure 6	2.0	0.8	-	2.0	-	ns

11. Waveforms



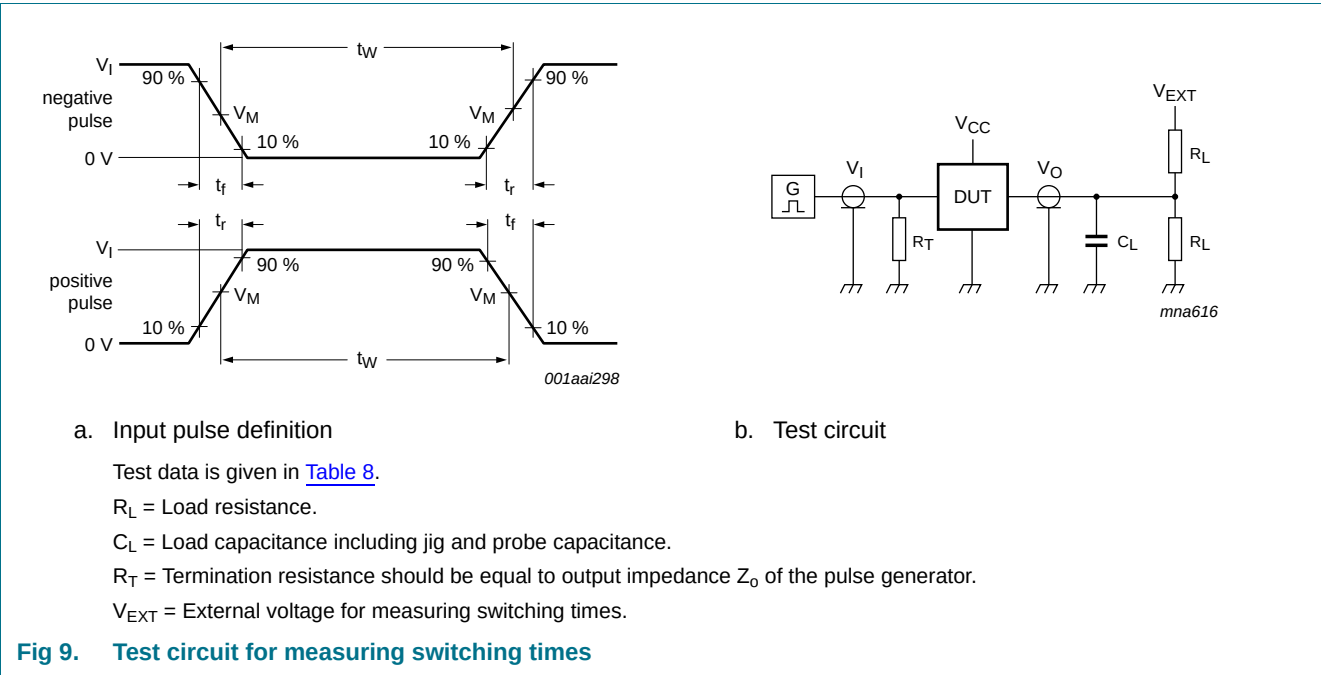
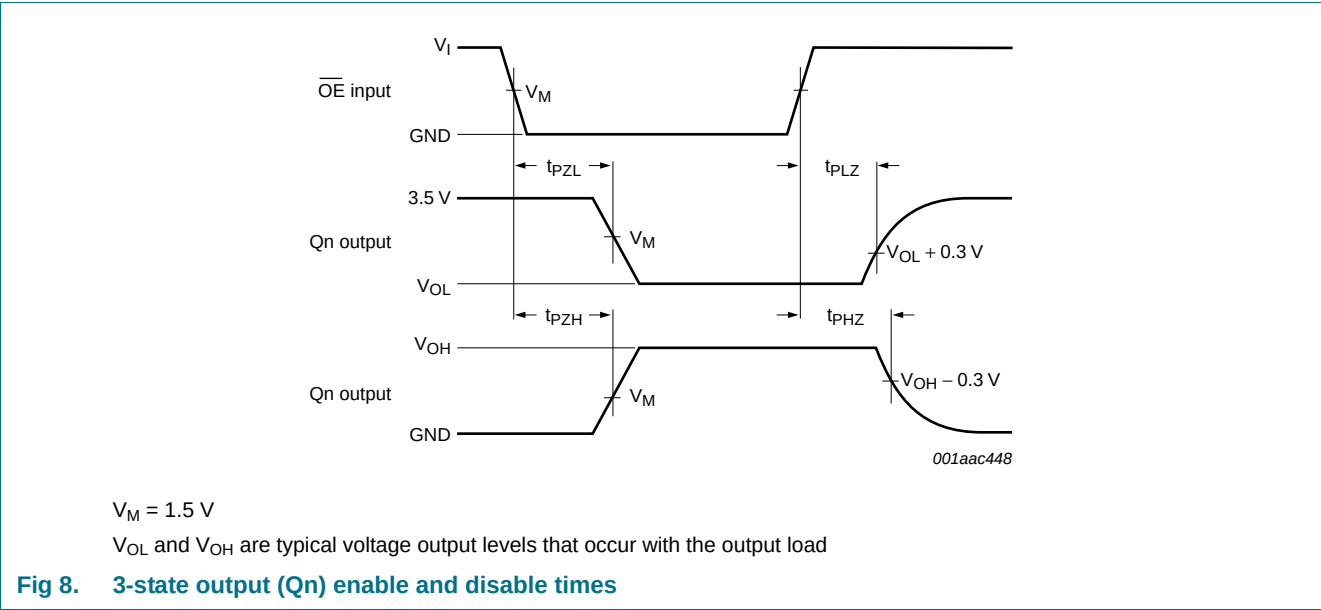


Table 8. Test data

Input				Load		V_{EXT}		
V_I	f_i	t_W	t_r, t_f	C_L	R_L	t_{PHL}, t_{PLH}	t_{PZH}, t_{PHZ}	t_{PZL}, t_{PLZ}
3.0 V	1 MHz	500 ns	$\leq 2.5\text{ ns}$	50 pF	500 Ω	open	open	7.0 V

12. Package outline

DIP20: plastic dual in-line package; 20 leads (300 mil)

SOT146-1

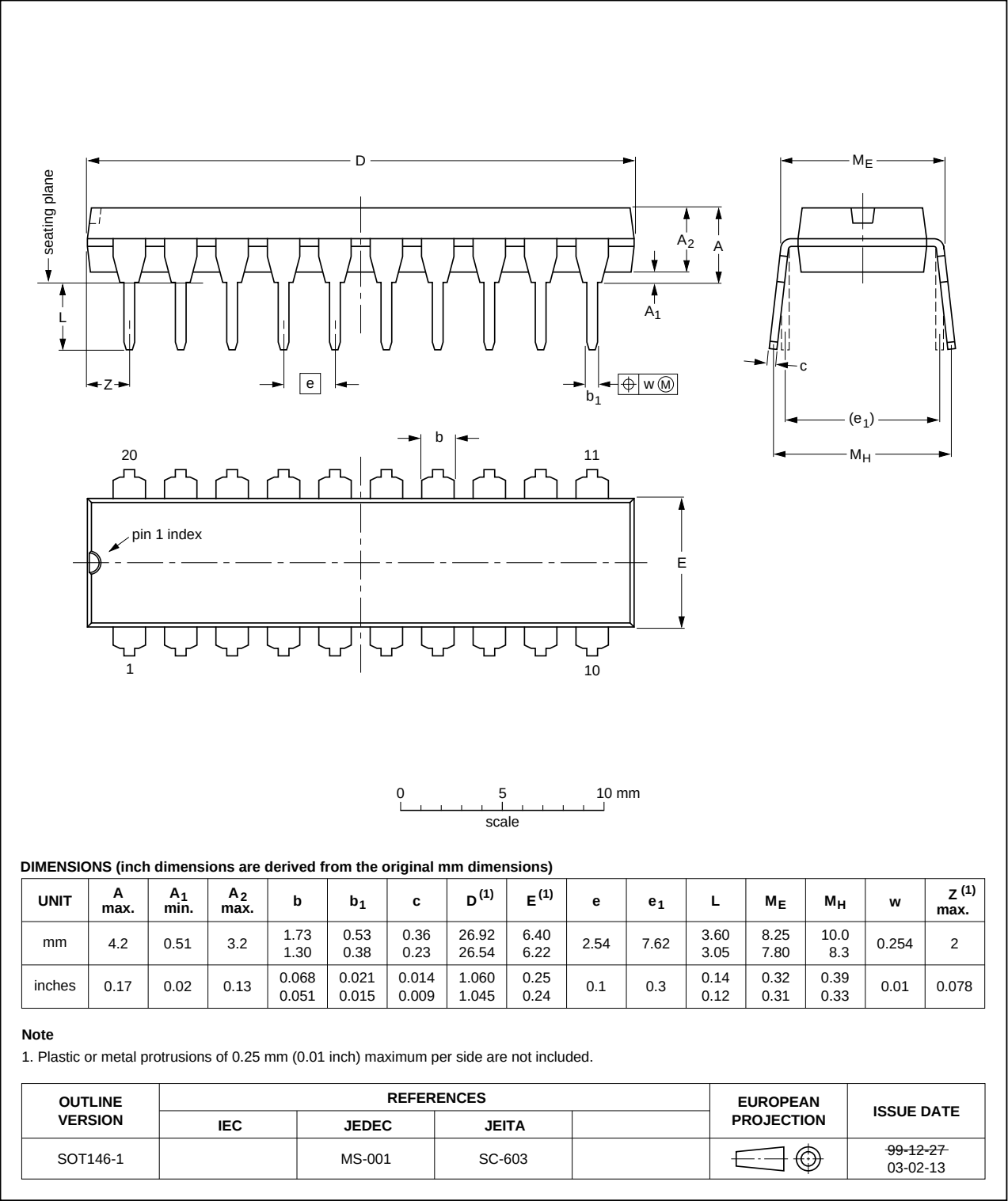


Fig 10. Package outline SOT146-1 (DIP20)

SO20: plastic small outline package; 20 leads; body width 7.5 mm

SOT163-1

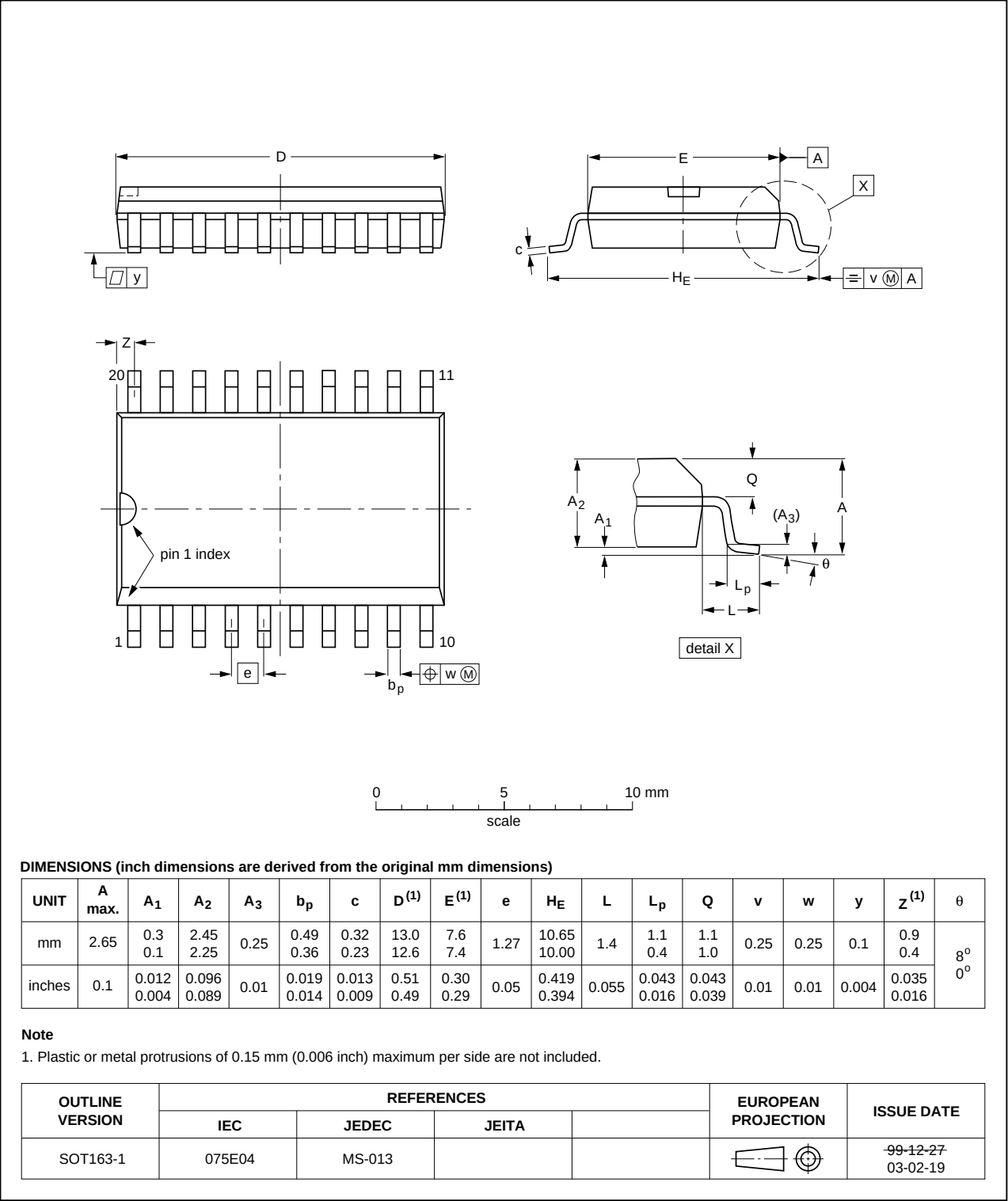


Fig 11. Package outline SOT163-1 (SO20)

SSOP20: plastic shrink small outline package; 20 leads; body width 5.3 mm

SOT339-1

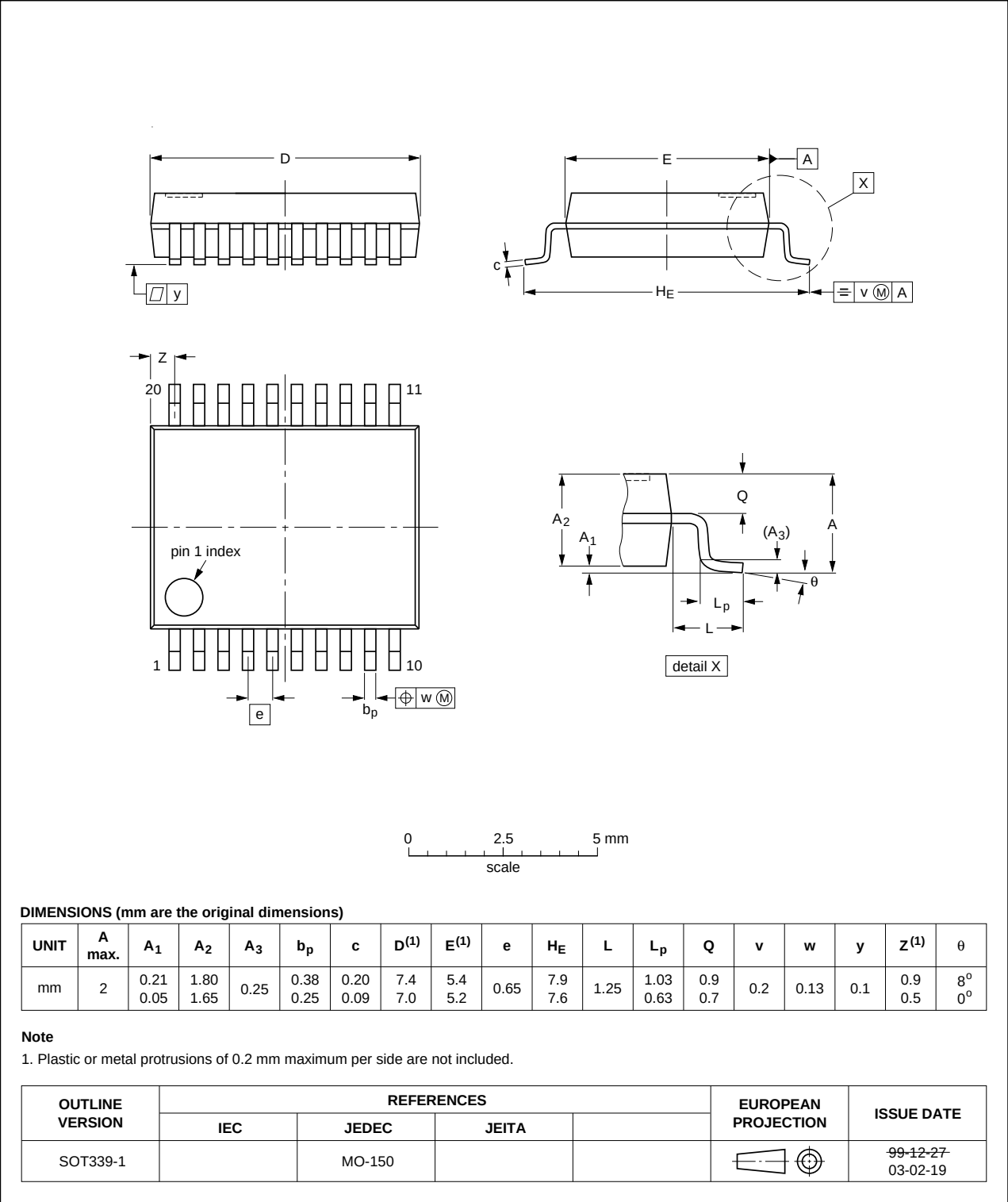


Fig 12. Package outline SOT339-1 (SSOP20)

TSSOP20: plastic thin shrink small outline package; 20 leads; body width 4.4 mm

SOT360-1

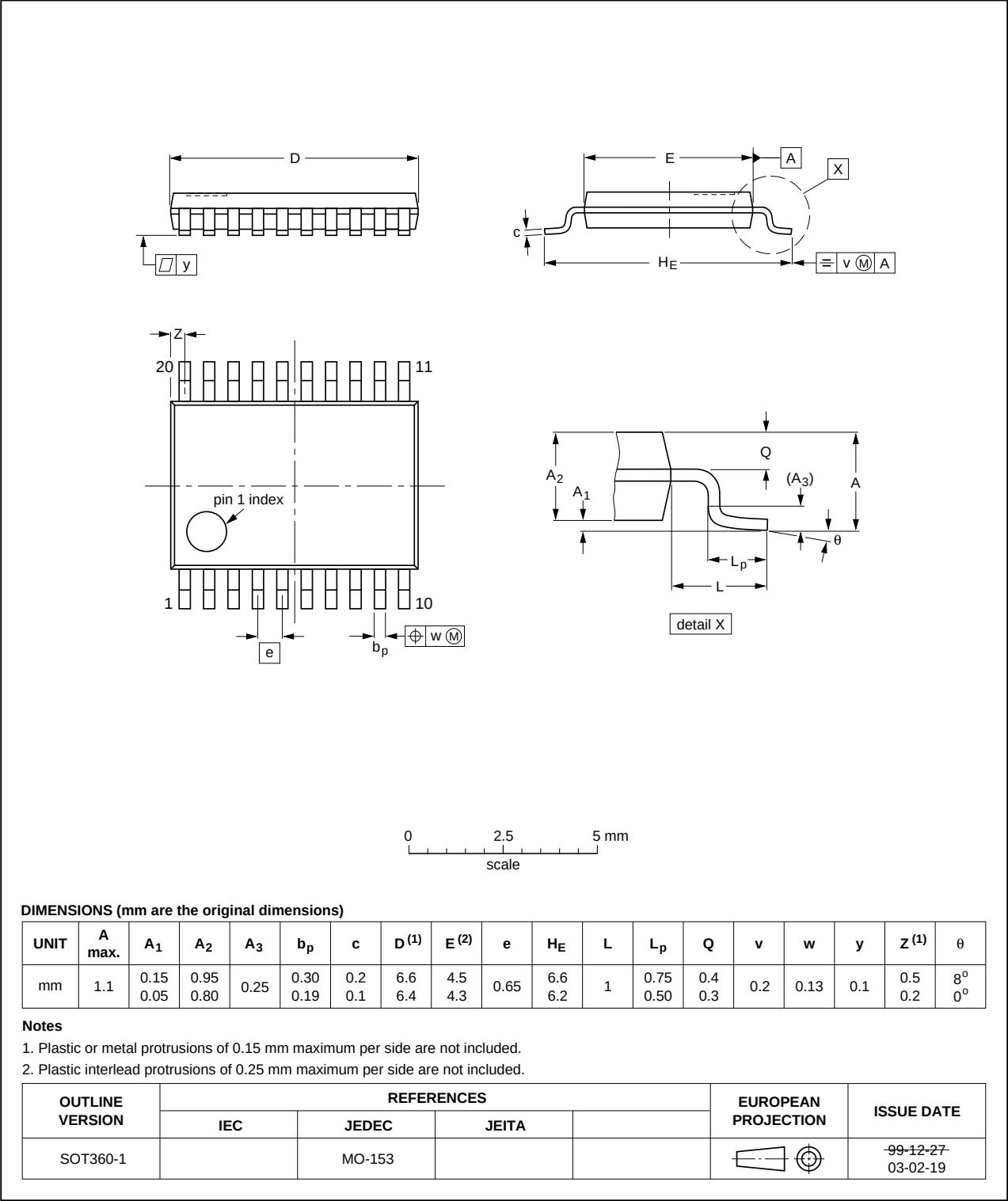


Fig 13. Package outline SOT360-1 (TSSOP20)

13. Abbreviations

Table 9. Abbreviations

Acronym	Description
BICMOS	Bipolar Complementary Metal-Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model
MM	Machine Model

14. Revision history

Table 10. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74ABT574A v.2	20121123	Product data sheet	-	74ABT574A v.1
Modifications:	- The format of this data sheet has been redesigned to comply with the new identity guidelines of NXP Semiconductors. - Legal texts have been adapted to the new company name where appropriate.			
74ABT574A v.1	19950522	Product specification	-	-

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Document status ^{[1][2]}	Product status ^[3]	Definition
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Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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Date of release: 23 November 2012

Document identifier: 74ABT574A